NSN 5961-01-257-3586

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-257-3586 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.370 inches **End Application:** Nsn 5895-01-277-2680; control, receiver-transmitter **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205af **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case and quality assurance level tx **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 drain to gate voltage and -100.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** -6.50 amperes drain current **Power Rating Per Characteristic:** 25.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

A110a0

No Fiig:

Demilitarization:

NSN 5961-01-257-3586

Transistor - Page 2 of 2



Mil-std (military Standard):

Mil-prf-19500 spec.